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Elnaz Rostampour (✉ el_rostampour@yahoo.com)

Islamic Azad University

Research Article

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Investigation of quantum transport and local density of states in a graphene strip connected to a square lattice

E Rostampour

Young Researchers and Elites club, Science and Research Branch, Islamic Azad University, Tehran, Iran

el_rostampour@yahoo.com

Abstract

We theoretically express quantum transport at Dirac points via graphene quantum billiard as a non-magnetic material to connect metallic leads. Our results indicate that the quantum billiard of graphene is similar to a resonant tunnelling device. The centerpiece size and the Fermi energy of the graphene quantum billiard play an important role in the resonant tunnelling. In graphene, change of carrier density can affect plasmon polaritons. At the Dirac point, the conductivity of graphene depends on the geometry, so that the conduction of the evanescent modes is close to the theoretical value of $4e^2/\pi h$ (where Planck's constant and the electron charge are denoted by h and e , respectively.). This transport property can be used to justify chaotic quantum systems and ballistic transistors. Our theoretical results demonstrate that the local density of state of the graphene sheet for $\epsilon_L = \epsilon_R = 0$ is larger than $\epsilon_L = \epsilon_R = t$ (where ϵ_L (ϵ_R) is onsite energy of the left (right) metallic lead) unlike the current obtained from the calculations.

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1. Introduction

Recently, tunnelling magnetoresistance (TMR) effect of hybrid materials with both organic molecules and ferromagnetic materials has studied for junctions [1, 2] and granular substances [3]. At normal incidence, Klein tunnelling in graphene is considered to be completely transparent of barriers, as was done by Katsnelson et al. [4] and experimentally [5], causing undesired charge leakage in graphene devices. Lack of Klein tunnelling [6] in Particle Physics unlike graphene, encapsulated electrons seem to be a practical and challenging task. In graphene-based nano-devices, the confinement of carriers is enhanced, such as p - n junction [7], superlattices [8] and FET [9]. To control quantum transport in graphene nanorings, the effects of interference of transport of coherent electron are considered by ignoring potential barriers. In the case mentioned, research conducted by Wu et al. [10] has shown that the behavior of the device is similar to resonance tunnelling, and the external magnetic field or the size of the device is effective in regulating the resonant energy. By applying the electrostatic potential to an arm on the Aharonov-Bohm magnetoconductance, its effects can be examined in [11]. Pel *et al.* [12] showed that fluctuations in mesoscopic conductivity in graphene depend of the Hamilton

symmetry properties, indicating the nontrivial universality of graphene. In disordered monolayer graphene, valley symmetry on UCF has also studied. There is a linear 2D energy spectrum near the Dirac points, and the moving electrons have a constant speed, and the band velocity of $v_F = 10^6$ m/s. The dispersion relation in graphene has interesting electronic properties similar to relativistic and massless fermions. In a hexagonal carbon lattice, such as single-walled carbon nanotubes, charge carriers play an important role in electronic transport [13, 14]. High mobility graphene specimens are used to make mesoscopic graphene devices. In this work, we study quantum transport in graphene quantum billiard with ferromagnetic leads.

2. Methodology

A graphene strip with lattice parameter a is considered as in Figure 1, which is connected on both sides by metallic leads to a square lattice with the same lattice parameter [15]. Hamiltonian of this model is usually described as:

$$H = H_C + \sum_{\alpha=L,R} (H_\alpha + H_{\alpha C}) \quad (1)$$

The first term of equation (1) is channel Hamiltonian that described by tight binding model:

$$H_C = \sum_{\langle i,j \rangle, \sigma} t (c_{i,\sigma}^\dagger c_{j,\sigma} + H.c.) \quad (2)$$

We determine the hopping integral at the bond $\langle i,j \rangle$, with $t = t_0 + t_0 e^{ik_y}$ if $i = 1,5,9, \dots$ and $0 < i < N-1$, $t = t_0$ if $i = 2,6,10, \dots$ and $0 < i < N-1$, $t = t_0 + t_0 e^{-ik_y}$ if $i = 3,7,11, \dots$ and $0 < i < N-1$ and $t = t_0$ if $i = 4,8,12, \dots$ and $0 < i < N-1$. In the above equation, t_0 is hopping integral between nearest neighbour i th and j th sites of the ideal system, k_y is the momentum in the y direction in the range $-\frac{\pi}{a} < k_y < \frac{\pi}{a}$ and the sum is on the nearest neighboring atoms $\langle i,j \rangle$. The annihilation operator is denoted by $c_{i,\sigma}$ for electron π at the site i with spin σ [spin-up ($\uparrow$) or spin-down ($\downarrow$)]. The left (right) metallic lead Hamiltonian is also expressed by the tight binding model. The Hamiltonian of left (L) and right (R) electrodes, H_α , is described as:

$$H_\alpha = \sum_{i,\alpha} \epsilon_{i,\alpha} c_{i,\alpha}^\dagger c_{j,\alpha,\sigma} \quad (3)$$

Here, $\epsilon_L(\epsilon_R)$ is onsite energy of left (right) metallic lead, $t_L(t_R)$ is nearest neighbor hopping amplitudes of left (right) metallic lead, $\epsilon_{i,\alpha}$ is $\epsilon_{i,L} = \epsilon_L + 2t_L \cos k_y$ ($\epsilon_{i,R} = \epsilon_R + 2t_R \cos k_y$) of left (right) electrode. The coupling matrix is expressed by $H_{\alpha C}$ between surface atomic orbital of leads and channel as:

$$H_{\alpha C} = \sum_{\alpha=L,R} \sum_{i\alpha,j\alpha,\sigma} -t'_\alpha (c_{i\alpha,\sigma}^\dagger d_{j\alpha,\sigma} + h.c.) \quad (4)$$

Where $t'_L(t'_R)$ is hopping amplitude between graphene sample and left (right) lead (for $i=0$ and N). The spin-up ($\uparrow$) current plus the spin-down ($\downarrow$) current is total current [16-19] as:

$$I(V_b, V_g) = \frac{e}{h} \int_{-\infty}^{+\infty} [f(\epsilon - \mu_L) - f(\epsilon - \mu_R)] T(\epsilon, V_b, V_g) d\epsilon \quad (5)$$

where e , h , f and $\mu_{L,R} = E_f \pm \frac{1}{2}eV_b$ are electron charge, Planck's constant, Fermi-Dirac distribution function and electrochemical potentials of right and left electrodes, respectively. The dependence of the transmission functions on gate and bias voltages, spin and energy is shown by the relation $T^\sigma(\varepsilon, V_b, V_g) = \text{tr}[\Gamma_L^\sigma G_{c,\sigma}^R \Gamma_R^\sigma G_{c,\sigma}^A]$, where $G_{c,\sigma}^{R(A)}$, $\Gamma_{L(R)}^\sigma = i(\Sigma_{L(R),\sigma} - \Sigma_{L(R),\sigma}^\dagger)$ and $\Sigma_{L(R),\sigma}$ are retarded (advanced) Green's function with σ spin, the injection ratio, and the self-energy with σ spin at sites 1 (N), respectively,

$$\Sigma_{L(N),\sigma}(\varepsilon) = t_{L(N)}' e^{-ik_{L(R),\sigma}}$$

with

$$k_{L(R),\sigma} = \arccos\left(\frac{\varepsilon - \epsilon_{L(R)} - 2t_{L(R)} \cos k_y}{2t_{L(R)}}\right). \quad (6)$$

Despite the bias voltage, the Green function of the system can be obtained by using the effective Hamiltonian of the molecule (H_c) and self-energy functions (Σ):

$$G_{c,\sigma}^{R,A}(\varepsilon) = \frac{1}{(\varepsilon \pm i\eta)I + H_c - \Sigma_{L,\sigma} - \Sigma_{R,\sigma}} \quad (7)$$

Where $\eta=0^+$ is considered a positive infinitesimal constant. Finally, the density of state function is as: $\text{DOS}(\varepsilon) = \frac{1}{2\pi} \text{Tr}(A(\varepsilon))$ where is calculated from the density of state matrix $A(\varepsilon) = i(G^R - G^A)$.

3. Results and discussions

Based on the two-atom basis, the group velocities of the Bloch *ansatz* is very high near those points at $\sim 8.5 \times 10^5$ m/s, indicating an effective "speed of light" in the comparison of massless Dirac fermions. The π and π^* zone-center Γ energies symmetrically to E_F represent the orthogonal tight binding model. When the overlap integral is not zero, the antibonding π^* bands are at higher energies. The parameter $\pi - \pi^*$ has similar results (Reich et al., 2002), as well as more accurate calculations of first-principles. The effects beyond nearest neighbor interactions and the so-called trigonal warping correction can also be examined. Periodic conduction fluctuations with bias and gate voltage are caused by quantum interference of graphene at low temperatures by multiply-reflected waves of electrons and holes. Graphene is considered as quantum billiard with long phase coherence length of more than 5 μm [20]. The experimental concept of Andreev billiard in graphene is the long phase coherence length of charges. Such a device represents the new Josephson junction in which the electron system in normal metal is Dirac fermions, not a Fermi Liquid. These junctions are predicted to exhibit a number of novel phenomena, such as Andreev reflection look like mirror [21, 22], Andreev electrons with a new type of propagating mode in the normal metal channel [23], and fluctuation of transmission probability depending on the width of the barrier [24]. In mesoscopic systems, fluctuations in quantum conductivity within the carrier confinement to a phase space with decreasing dimensions are visible [25-28]. The results obtained for the I-V characteristics of graphene are depicted in Figure 2 by value of k_y (adjacent to Dirac point), $(\frac{4\pi}{3a})$, that the current by increasing the voltage increases. Bias voltages are reasonable in practical experimental measurements in the range from 0.0 to 2 V. Current doesn't drop in graphene attached to square lattice leads. For $t_L = t_R = \epsilon_L = \epsilon_R = t$ we obtain a larger current than when $t_L = t_R = t$, $\epsilon_L = \epsilon_R = 0$. By changing the lead energy band centers, these values change. Recently several groups

have performed non-local four-probe measurements [29, 30, 31] in graphene, attached to a ferromagnetic electrode, where there are spin currents between injector and detector. At room temperature, graphene experiments with a spin relaxation length greater than $2\mu\text{m}$ allow the injection of a spin current [29]. In graphene connected to two ferromagnetic electrodes, a magnetic resistance of several hundred Ohms is visible in the rotation valve [32] which is also used in spintronic devices. Lead-determining parameters affect the conductance, $G = \frac{e^2}{h} \frac{2g_s g_v}{\pi} \frac{W}{L} \frac{\sin k_L \sin k_R}{\sin(k_L + k_R)} \arctan\left(\frac{\sin(k_L + k_R)}{1 - \cos(k_L + k_R)}\right)$ where W and L are the wide and length of the graphene sample, respectively. The $g_{s(v)} = 2$ is the spin (valley) degeneracy. The relations k_L and k_R show the dependence of conductance only on the parameters of the lead via t_L and t_R . The conductance in terms of the function of t_L and t_R at the Dirac points, $(0, \frac{4\pi}{3a})$, is plotted in Figure 3. The probability of transmission in terms of a function of energy with $t_L = t_R = \epsilon_L = \epsilon_R = t$ and $t_L = t_R = t$, $\epsilon_L = \epsilon_R = 0$ at the Dirac point $(\frac{4\pi}{3a})$ represents at bias of 0V in the fig.4. Near the Dirac points of graphene, the probability of transmission can be examined from the point of view of the excitations of a virtual electron-hole pair close to zero energy [33]. Transmission resonances depend on doping and confinement in the quantum transport. To expand the energy level, the effect of self-energy is used, which due to the rule of sum, its integrated strength does not change. The self-energy method allows us investigate in detail the local density of states (LDOS) in different parts of graphene. LDOS tells us the number of energy Eigen-state per unit energy range and it depends on dispersion relation. The size quantization effects modify it. In Fig.5, LDOS of the graphene at the left end and right end are depicted as a function of E (eV) that is equal for the two ends. LDOS of the graphene at the Dirac point for $t_L = t_R = t$, $\epsilon_L = \epsilon_R = 0$ is larger than $t_L = t_R = \epsilon_L = \epsilon_R = t$ (Fig.5-(b)). Plasmon propagation distance is checked from experimental data calculated LDOS diagrams in Ref. 34.

Localized graphene plasmon resonance in the LDOS model is generated in localized modes for specific values of bandwidth ($W=0.37\lambda_p$ and $0.82\lambda_p$) near the graphene ribbon strip. To increase the plasmon-dipole interaction and the signal in the near-field, a strong concentration of electromagnetic field is used [34]. In theory and experiment, the profiles of the two localized modes and the conventional Fabry-Perot cavity modes are both completely different from each other. At the edges of the graphene there is a maximum field in the lowest order mode and in the middle there is a maximum field in the lowest order of conventional Fabry-Prote mode. It should be noted that the reflection coefficient of graphene plasmons at the boundaries is approximately one (zero phase).

Figure 1. A graphene sample attached to metallic leads and matched square lattices connected to it.

Figure 2. Current versus voltage characteristics for graphene with $t_L = t_R = \epsilon_L = \epsilon_R = t$ (solid plot (-)) and $t_L = t_R = t$, $\epsilon_L = \epsilon_R = 0$ (dashed plot (-)).

Figure 3. Conductance evaluated at the Dirac points, $\varepsilon = 0$, (a) $k_y = 0$, (b) $k_y = \frac{4\pi}{3a}$, in terms of the source and drain leads parameters.

Figure 4. The probability of transmission in terms of energy at $V_b = 0V$ with $t_L = t_R = \epsilon_L = \epsilon_R = t$ (solid plot (-)) and $t_L = t_R = t$, $\epsilon_L = \epsilon_R = 0$ (dashed plot (-)).

Figure 5. LDOS (a) at left end of graphene, (b) of the graphene for $i=1, N$ and (c) at right end of graphene with $t_L = t_R = \epsilon_L = \epsilon_R = t$ (solid plot (-)) and $t_L = t_R = t$, $\epsilon_L = \epsilon_R = 0$ (dashed plot (-)).

4. Conclusions

The quantum transport is discussed in graphene quantum billiard by non-equilibrium Green function method. Here we have the increase in current with the increase in voltage. The graphene quantum billiard is suggested for the operation of devices with a nanoscale current. Our theoretical results indicate that the local density of state is equal in the left and right metallic leads. Furthermore, onsite energies of left and right metallic leads (ϵ_L and ϵ_R) affect the quantum transport through graphene quantum billiard with ferromagnetic leads.

Conflict of Interest

The author declares that she has no conflict of interest.

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Figures

Figure 1

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Figure 2

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Figure 3

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Figure 4

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Figure 5

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